

VOLTAGE RANGE: 40 - 200V

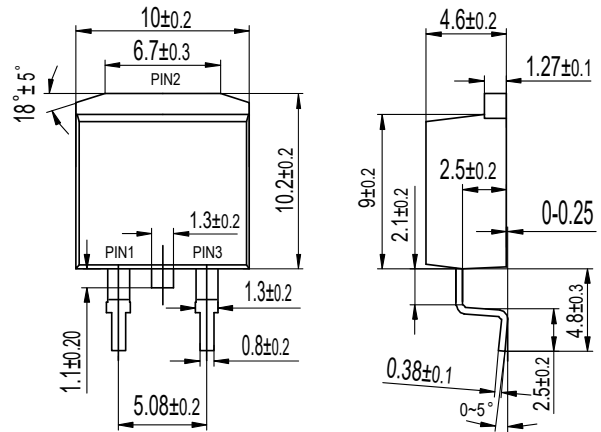
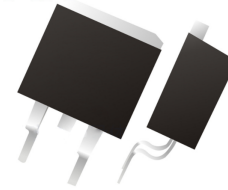
CURRENT: 40A

Features

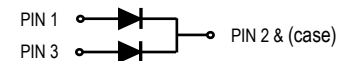
- High efficiency operation
- Low power loss
- Low stored charge majority carrier conduction
- High forward surge capability
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std (Halogen Free)

Mechanical Data

- Circuit figure: Single positive
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: TO-263(D²PAK) 1.35 grams



TO-263(D²PAK)



Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

RATINGS	SYMBOL	MBRB 40H40CT	MBRB 40H45CT	MBRB 40H60CT	MBRB 40H100CT	MBRB 40H150CT	MBRB 40H200CT	UNIT
Maximum repetitive reverse voltage	VRRM	40	45	60	100	150	200	V
Maximum RMS voltage	VRMS	28	32	42	70	105	140	V
Maximum DC blocking voltage	VDC	40	45	60	100	150	200	V
Maximum average forward current per device per diode	IAV	40 20						A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	IFSM	380						A
Typical thermal resistance (Note 1)	Rθ-JC	2.5						°C/W
Operating junction temperature range	TJ	-55 to +150				-55 to +175		°C
Storage temperature range	TSTG	-55 to +175						°C
Maximum forward voltage per leg at IF=20A	VF	0.65		0.75	0.85	0.95		V
Maximum average reverse current at rated DC blocking voltage TJ=25°C TJ=125°C	IR	0.10 20			0.01 8			mA

Notes: 1. Thermal resistance from junction to case.

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

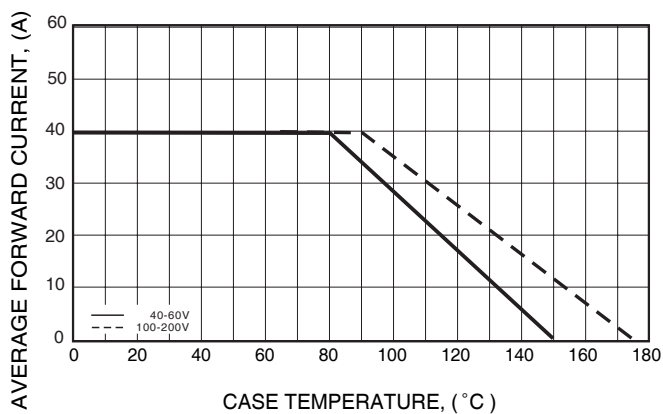


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

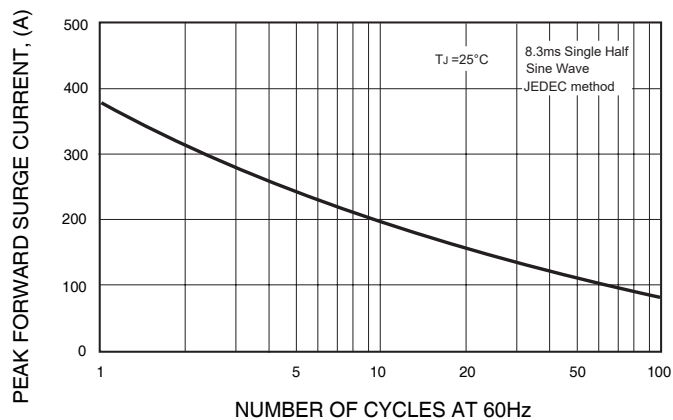


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

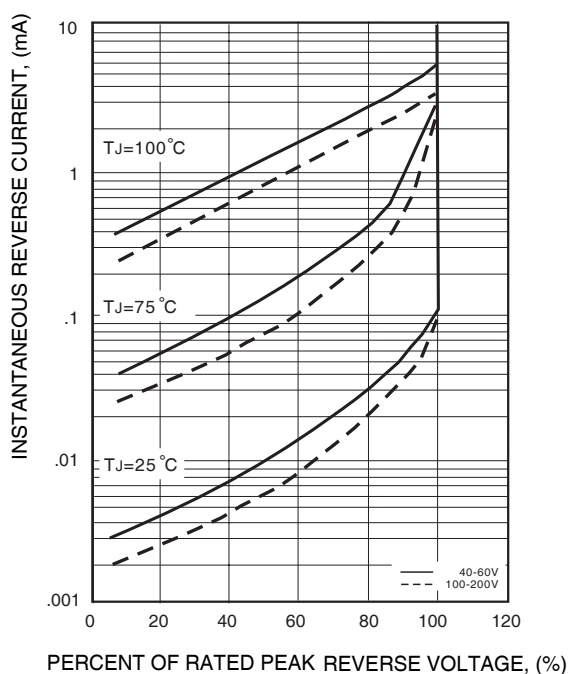


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

